

March 2007

74ACQ241 Octal Buffer/Line Driver with 3-STATE Outputs

Features

- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Improved latch-up immunity
- 3-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24mA
- Faster prop delays than the standard AC

General Description

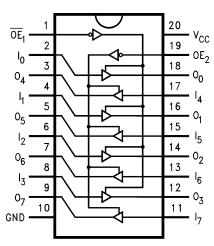
The ACQ241 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The ACQ utilizes Fairchild FACT Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Ordering Information

| Order Number | Package Number | Package Description |
|--------------|-------------------|--|
| 74ACQ241SC | M20B | 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide |

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

Connection Diagram



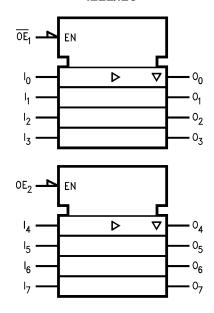
Pin Descriptions

| Pin Names | Description | | | |
|--------------------------------|------------------------------|--|--|--|
| \overline{OE}_1 , OE_2 | 3-STATE Output Enable Inputs | | | |
| I ₀ —I ₇ | Inputs | | | |
| O ₀ –O ₇ | Outputs | | | |

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Logic Symbol

IEEE/IEC



Truth Table

| Inp | uts | Outputs |
|-----------------|-----|-----------------------|
| ŌE ₁ | In | (Pins 12, 14, 16, 18) |
| L | L | L |
| L | Н | Н |
| Н | Х | Z |

| Inp | uts | Outputs |
|-----------------|-----|-------------------|
| OE ₂ | In | (Pins 3, 5, 7, 9) |
| Н | L | L |
| Н | Н | Н |
| Н | Х | Z |

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = High Impedance

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameter | Rating |
|-------------------------------------|---|---------------------------------|
| V _{CC} | Supply Voltage | -0.5V to +7.0V |
| I _{IK} | DC Input Diode Current | |
| | $V_1 = -0.5V$ | –20mA |
| | $V_{I} = V_{CC} + 0.5V$ | +20mA |
| V _I | DC Input Voltage | –0.5V to V _{CC} + 0.5V |
| I _{OK} | DC Output Diode Current | |
| | $V_{O} = -0.5V$ | –20mA |
| | $V_{O} = V_{CC} + 0.5V$ | +20mA |
| V _O | DC Output Voltage | –0.5V to V _{CC} + 0.5V |
| Io | DC Output Source or Sink Current | ±50mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current per Output Pin | ±50mA |
| T _{STG} | Storage Temperature | −65°C to +150°C |
| | DC Latch-Up Source or Sink Current | ±300mA |
| TJ | Junction Temperature | 140°C |

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Symbol | Parameter | Rating |
|-----------------|--|-----------------------|
| V _{CC} | Supply Voltage | 2.0V to 6.0V |
| V _I | Input Voltage | 0V to V _{CC} |
| Vo | Output Voltage | 0V to V _{CC} |
| T _A | Operating Temperature | -40°C to +85°C |
| ΔV / Δt | Minimum Input Edge Rate | 125mV/ns |
| | $V_{\rm IN}$ from 30% to 70% of $V_{\rm CC}$, $V_{\rm CC}$ @ 3.0V, 4.5V, 5.5V | |

DC Electrical Characteristics

| | | | | T _A = - | +25°C | T _A = -40°C to +85°C | |
|--------------------------------|---|---------------------|---|--------------------|--------|---------------------------------|-------|
| Symbol | Parameter | V _{CC} (V) | Conditions | Тур. | G | uaranteed Limits | Units |
| V _{IH} | Minimum High Level | 3.0 | $V_{OUT} = 0.1V$ | 1.5 | 2.1 | 2.1 | V |
| | Input Voltage | 4.5 | or V _{CC} – 0.1V | 2.25 | 3.15 | 3.15 | |
| | | 5.5 | | 2.75 | 3.85 | 3.85 | |
| V _{IL} | Maximum Low Level | 3.0 | $V_{OUT} = 0.1V$ or | 1.5 | 0.9 | 0.9 | V |
| | Input Voltage | 4.5 | V _{CC} – 0.1V | 2.25 | 1.35 | 1.35 | |
| | | 5.5 | | 2.75 | 1.65 | 1.65 | |
| V _{OH} | Minimum High Level | 3.0 | $I_{OUT} = -50\mu A$ | 2.99 | 2.9 | 2.9 | V |
| | Output Voltage | 4.5 | | 4.49 | 4.4 | 4.4 | |
| | | 5.5 | | 5.49 | 5.4 | 5.4 | |
| | | | $V_{IN} = V_{IL}$ or V_{IH} : | | | | V |
| | | 3.0 | $I_{OH} = -12mA$ | | 2.56 | 2.46 | |
| | | 4.5 | $I_{OH} = -24mA$ | | 3.86 | 3.76 | |
| | | 5.5 | $I_{OH} = -24 \text{mA}^{(1)}$ | | 4.86 | 4.76 | |
| V _{OL} | Maximum Low Level | 3.0 | $I_{OUT} = 50\mu A$ | 0.002 | 0.1 | 0.1 | V |
| | Output Voltage | 4.5 | | 0.001 | 0.1 | 0.1 | |
| | | 5.5 | | 0.001 | 0.1 | 0.1 | |
| | | | $V_{IN} = V_{IL}$ or V_{IH} : | | | | V |
| | | 3.0 | $I_{OL} = 12mA$ | | 0.36 | 0.44 | |
| | | 4.5 | I _{OL} = 24mA | | 0.36 | 0.44 | |
| | | 5.5 | $I_{OL} = 24 \text{mA}^{(1)}$ | | 0.36 | 0.44 | |
| I _{IN} ⁽³⁾ | Maximum Input Leakage Current | 5.5 | $V_I = V_{CC}$, GND | | ± 0.1 | ± 1.0 | μA |
| I _{OLD} | Minimum Dynamic | 5.5 | V _{OLD} = 1.65V Max. | | | 75 | mA |
| I _{OHD} | Output Current ⁽²⁾ | 5.5 | V _{OHD} = 3.85V Min. | | | – 75 | mA |
| I _{CC} ⁽³⁾ | Maximum Quiescent Supply Current | 5.5 | $V_{IN} = V_{CC}$ or GND | | 4.0 | 40.0 | μA |
| I _{OZ} | Maximum 3-STATE Leakage Current | 5.5 | $\begin{aligned} &V_{I}\left(OE\right) = V_{IL}, V_{IH}; \\ &V_{I} = V_{CC}, GND; \\ &V_{O} = V_{CC}, GND \end{aligned}$ | | ± 0.25 | ± 2.5 | μА |
| V _{OLP} | Quiet Output Maximum Dynamic V _{OL} | 5.0 | Figures 1 & 2 ⁽⁴⁾ | 1.1 | 1.5 | | V |
| V _{OLV} | Quiet Output Minimum Dynamic V _{OL} | 5.0 | Figures 1 & 2 ⁽⁴⁾ | -0.6 | -1.2 | | V |
| V_{IHD} | Minimum High Level Dynamic Input Voltage | 5.0 | (5) | 3.1 | 3.5 | | V |
| V _{ILD} | Maximum Low Level Dynamic Input Voltage | 5.0 | (5) | 1.9 | 1.5 | | V |

Notes:

- 1. All outputs loaded; thresholds on input associated with output under test.
- 2. Maximum test duration 2.0ms, one output loaded at a time.
- 3. I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC} .
- 4. Max number of outputs defined as (n). Data Inputs are driven 0V to 5V. One output @ GND.
- 5. Max number of Data Inputs (n) switching. n-1 Inputs switching 0V to 5V. Input-under-test switching: 5V to threshold (V_{IHD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

| | | | T _A = +25°C, C _L = 50pF | | $T_A = -40$ °C to +85°C, $C_L = 50$ pF | | | |
|---------------------------------------|---|------------------------------------|--|------|---|------|------|-------|
| Symbol | Parameter | V _{CC} (V) ⁽⁶⁾ | Min. | Тур. | Max. | Min. | Max. | Units |
| t _{PHL} , t _{PLH} | Propagation Delay, | 3.3 | 2.0 | 6.5 | 9.0 | 2.0 | 9.5 | ns |
| | Data to Output | 5.0 | 1.5 | 4.5 | 6.0 | 1.5 | 6.5 | 1 |
| t _{PZL} , t _{PZH} | Output Enable Time | 3.3 | 2.5 | 8.0 | 13.0 | 2.5 | 13.5 | ns |
| | | 5.0 | 1.5 | 5.5 | 8.5 | 1.5 | 9.0 | 1 |
| t _{PHZ} , t _{PLZ} | Output Disable Time | 3.3 | 1.0 | 8.5 | 14.5 | 1.0 | 15.0 | ns |
| | | 5.0 | 1.0 | 5.5 | 9.5 | 1.0 | 10.0 | 1 |
| t _{OSHL} , t _{OSLH} | Output to Output Skew Data to Output ⁽⁷⁾ | 3.3 | | 1.0 | 1.5 | | 1.5 | ns |

Notes:

- 6. Voltage range 5.0 is 5.0V \pm 0.5V. Voltage range 3.3 is 3.3V \pm 0.3V.
- 7. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

| Symbol | Parameter | Conditions | Тур. | Units |
|-----------------|-------------------------------|------------------------|------|-------|
| C _{IN} | Input Capacitance | V _{CC} = OPEN | 4.5 | pF |
| C _{PD} | Power Dissipation Capacitance | V _{CC} = 5.0V | 70 | pF |

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

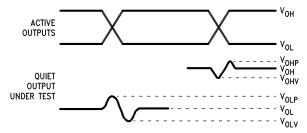
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

- 1. Verify Test Fixture Loading: Standard Load 50pF, 500Ω .
- Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
- Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
- Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
- Set the word generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope



Notes:

- V_{OHV} and V_{OLP} are measured with respect to ground reference.
- 9. Input pulses have the following characteristics: $f=1 MHz, \, t_r=3 ns, \, t_f=3 ns, \, skew < 150 ps.$

Figure 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable.
 Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{IL} D.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

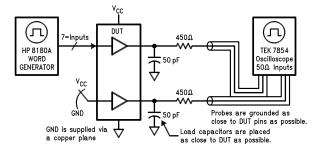
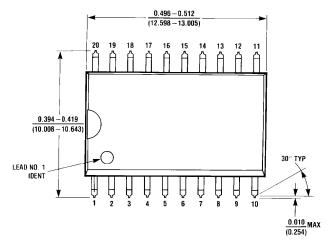
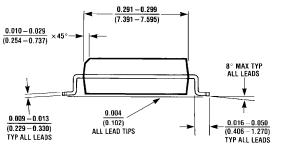


Figure 2. Simultaneous Switching Test Circuit

Physical Dimensions

Dimensions are in inches (millimeters) unless otherwise noted.





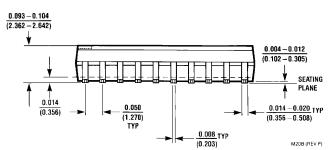


Figure 3. 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Package Number M20B





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